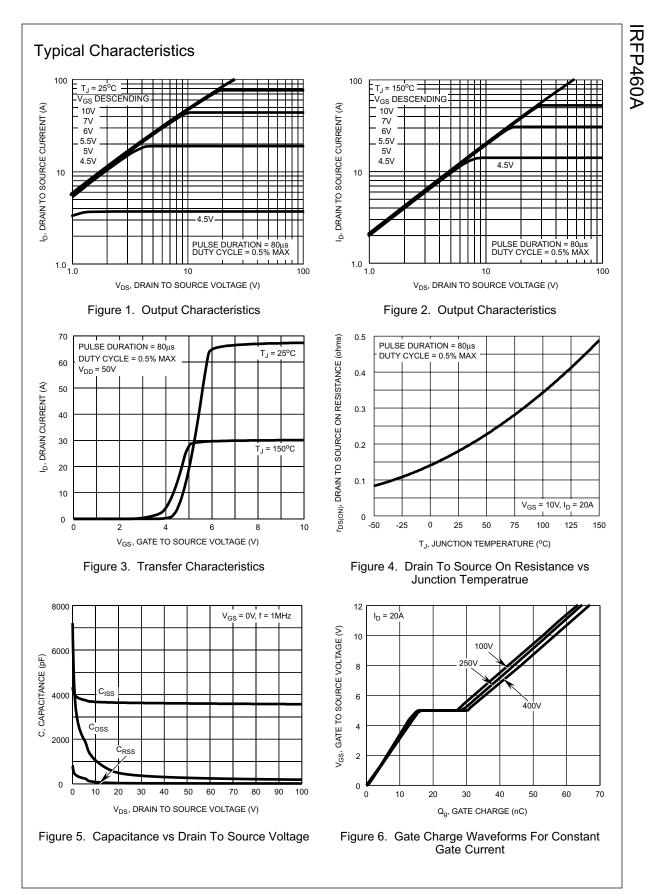
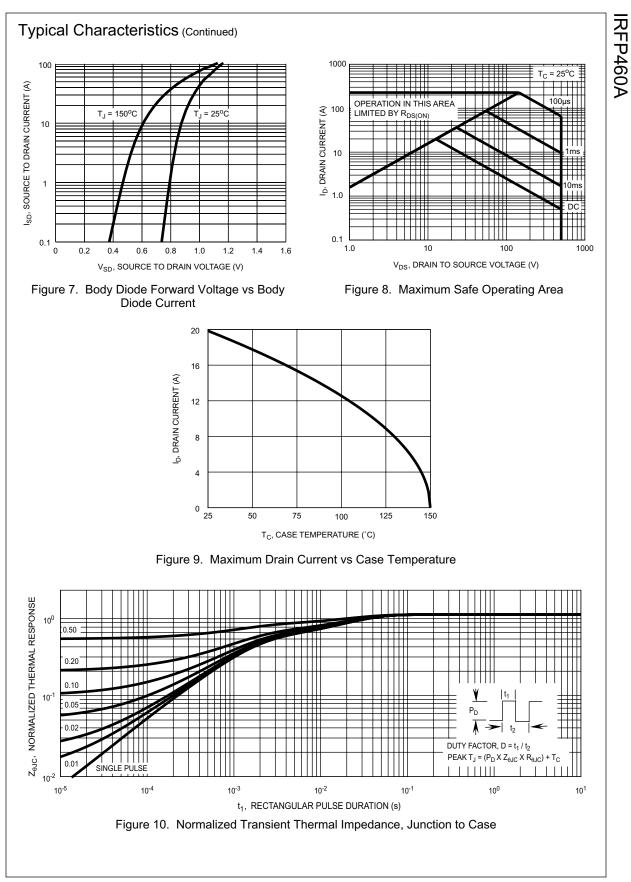


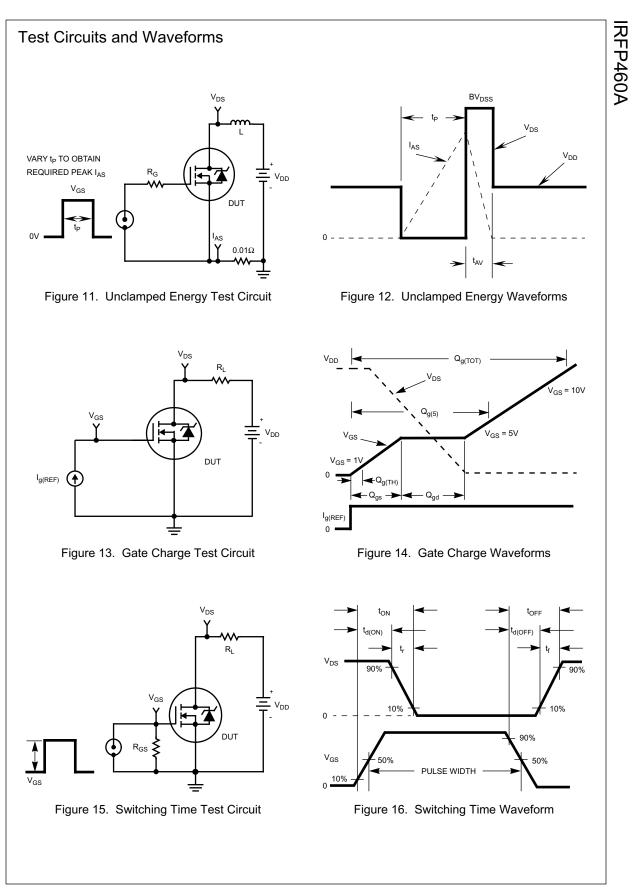
| Device Marking | | Device | Package | Reel Size | Tape Width | | Quantity | |
|-------------------------|---|---|---|---|------------|------|----------|-------|
| IRFP4 | 60A | IRFP460A | TO-247 | - | - | | - | |
| lectrical | Chara | cteristics T _J = 25°C (unle | ess otherwise no | oted) | | | | |
| Symbol | | Parameter | | Test Conditions | | Тур | Max | Units |
| tatics | | | | | | | | |
| B _{VDSS} | Drain to Source Breakdown Voltage | | I _D = 250μA, Υ | I _D = 250μA, V _{GS} = 0V | | - | - | V |
| $B_{VDSS}/\Delta T_{J}$ | Breakdown Voltage Temp. Coefficient | | V/°C Reference to 25° C, ID = 1mA | | - | 0.61 | - | |
| r _{DS(ON)} | Drin to Source On-Resistance | | V _{GS} = 10V, I _D = 12A | | - | 0.17 | 0.22 | Ω |
| V _{GS(th)} | Gate Threshold Voltage | | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | | 2.0 | 3.3 | 4.0 | V |
| I _{DSS} | Zero Gate Voltage Drain Current | | V _{DS} = 25V V _{GS} = 0V | $T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 150^{\rm o}{\rm C}$ | - | - | 25 | μA |
| | | | | | - | - | 250 | |
| I _{GSS} | Gate to Se | ource Leakage Current | V_{GS} = ±20V | | - | - | ±100 | nA |
| ynamics | | | | | | | | |
| g _{fs} | Forward T | Fransconductance | V _{DS} = 50V, I _I | ₀ = 12A | 11 | - | - | S |
| Q _{g(TOT)} | Total Gate | e Charge | V _{GS} = 10V, | | - | 56 | 70 | nC |
| Q _{gs} | Gate to Source Gate Charge V_{DS} = 400V,Gate to Drain "Miller" Charge I_D = 20ATurn-On Delay Time V_{DD} = 250V, | | V _{DS} = 400V, | | - | 13 | 18 | nC |
| Q _{gd} | | | $I_{\rm D} = 20$ A | | - | 17 | 22 | nC |
| t _{d(ON)} | | | | - | 13 | - | ns | |
| t _r | Rise Time |) | $I_{\rm D} = 20A$ | | - | 8 | - | ns |
| t _{d(OFF)} | Turn-Off Delay Time | | $R_{G} = 4.3\Omega,$ | | - | 41 | - | ns |
| t _f | Fall Time | • | $R_{\rm D} = 13\Omega$ | | - | 6 | - | ns |
| C _{ISS} | Input Cap | acitance | | | - | 3520 | - | pF |
| C _{OSS} | | Output Capacitance | | $V_{\rm DS} = 25V, V_{\rm GS} = 0V,$ | | 410 | - | pF |
| C _{RSS} | | Fransfer Capacitance | f = 1MHz | | - | 21 | - | pF |
| valanche | Charact | eristics | | | | | | |
| E _{AS} | | lse Avalanche Energy ² | | | 960 | - | - | mJ |
| I _{AR} | Avalanche | 6, | | | - | - | 20 | A |
| | | Avalanche Energy ¹ | | | 28 | - | | mJ |
| E _{AR} | | | | | 20 | | _ | 1110 |
| rain-Sour | | e Characteristics | | | | | | |
| I _S | (Body Dio | | MOSFET syr showing the | | - | - | 20 | A |
| I _{SM} | Pulsed Source Current ¹ (Body Diode) | | integral rever p-n junction of | | - | - | 80 | A |
| V_{SD} | Source to Drain Diode Voltage | | I _{SD} = 20A | | - | 0.86 | 1.8 | V |
| t _{rr} | Reverse Recovery Time | | - | _{SD} /dt = 100A/µs | - | 560 | 710 | ns |
| Q _{RR} | Reverse F | Recovered Charge | I _{SD} = 20A, dI | _{SD} /dt = 100A/μs | - | 8.0 | 11 | μC |
| | | limited by maximum junction tempera C, L = 7.0mH, R _G = 25 Ω , I _{AS} = 14A | ture | | | | | |

IRFP460A



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